

TECHNICAL DATA
DATA SHEET 303, REV. B
Formerly Part Number SHD2181A/B**HERMETIC POWER MOSFET
N-CHANNEL****FEATURES:**

- 60 Volt, 0.027 Ohm, 45A MOSFET
- Isolated Hermetic Metal Package
- Fast Switching
- Low $R_{DS(on)}$
- Equivalent to IRFM054 Series

MAXIMUM RATINGSALL RATINGS ARE AT $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	V_{GS}	-	-	± 20	Volts
ON-STATE DRAIN CURRENT @ $T_C = 25^\circ\text{C}$ $V_{GS} = 10\text{V}$ @ $T_C = 100^\circ\text{C}$	I_D	-	-	45 35	Amps
PULSED DRAIN CURRENT @ $T_C = 25^\circ\text{C}$	I_{DM}	-	-	220	Amps
OPERATING AND STORAGE TEMPERATURE	T_{OP}/T_{STG}	-55	-	+150	$^\circ\text{C}$
TOTAL DEVICE DISSIPATION @ $T_C = 25^\circ\text{C}$	P_D	-	-	200	Watts

ELECTRICAL CHARACTERISTICS

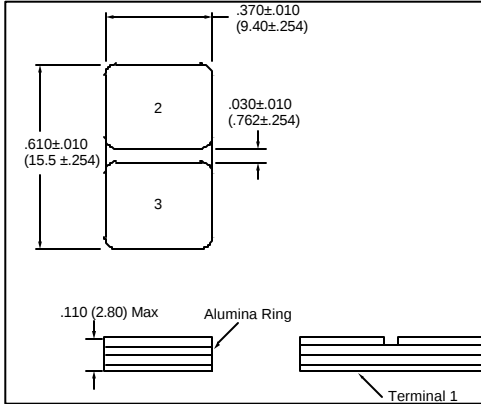
DRAIN TO SOURCE BREAKDOWN VOLTAGE $V_{GS} = 0\text{V}, I_D = 1.0\text{mA}$	BV_{DSS}	60	-	-	Volts
STATIC DRAIN TO SOURCE ON STATE RESISTANCE $V_{GS} = 10\text{V}, I_D = 35\text{A}$	$R_{DS(ON)}$	-	-	0.027	Ω
GATE THRESHOLD VOLTAGE $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	$V_{GS(th)}$	2.0	-	4.0	Volts
FORWARD TRANSCONDUCTANCE $V_{DS} \geq 15\text{V}, I_{DS} = 35\text{A}$	g_{fs}	20	-	-	$\text{S}(1/\Omega)$
ZERO GATE VOLTAGE DRAIN CURRENT $V_{DS} = 0.8 \times \text{Max. Rating}, V_{GS} = 0\text{V}$ $V_{DS} = 0.8 \times \text{Max. Rating}, V_{GS} = 0\text{V}, T_J = 125^\circ\text{C}$	I_{DSS}	-	-	25 250	μA
GATE TO SOURCE LEAKAGE FORWARD $V_{GS} = 20\text{V}$ GATE TO SOURCE LEAKAGE REVERSE $V_{GS} = -20\text{V}$	I_{GSS}	-	-	100 -100	nA
TURN ON DELAY TIME $V_{DD} = 30\text{V},$ RISE TIME $I_D = 35\text{A},$ TURN OFF DELAY TIME $R_G = 2.35\Omega$ FALL TIME	$t_{d(ON)}$ t_r $t_{d(OFF)}$ t_f	-	-	33 180 100 100	nsec
DIODE FORWARD VOLTAGE $T_C = 25^\circ\text{C}, I_S = 35\text{A},$ $V_{GS} = 0\text{V}$	V_{SD}	-	-	2.5	Volts
REVERSE RECOVERY TIME $T_J = 25^\circ\text{C},$ $I_F = 35\text{A},$ $di/ds \leq 100\text{A}/\mu\text{sec}, V_{DD} \leq 50\text{V}$	t_{rr}	-	-	280	nsec
INPUT CAPACITANCE $V_{GS} = 0\text{V}$ OUTPUT CAPACITANCE $V_{DS} = 25\text{V}$ REVERSE TRANSFER CAPACITANCE $f = 1.0\text{MHz}$	C_{iss} C_{oss} C_{rss}	-	4600 2000 340	-	pF
THERMAL RESISTANCE, JUNCTION TO CASE	R_{thJC}	-	-	0.6	$^\circ\text{C}/\text{W}$

SENSITRON

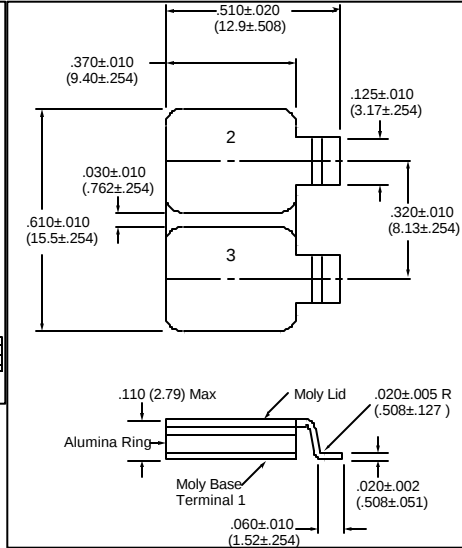
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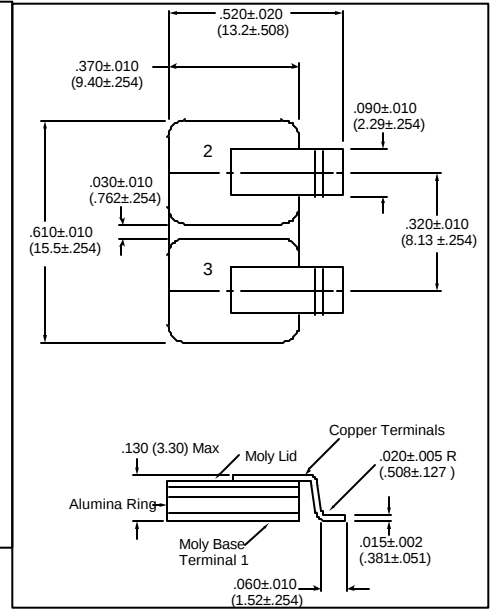
MECHANICAL DIMENSIONS: in Inches / mm



SHD-5



SHD-5A



SHD-5B

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET, SURFACE MOUNT	DRAIN	SOURCE	GATE
SHD-5, 5A, 5B PACKAGE			

TECHNICAL DATA

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